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FJNS3201R

Switching Application (Bias Resistor Built In)

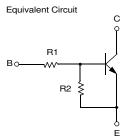
- Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor (R1=4.7K Ω , R2=4.7K Ω)
- Complement to FJNS4201R



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

| Symbol | Parameter | Value | Units |
|------------------|-----------------------------|-----------|-------|
| V _{CBO} | Collector-Base Voltage | 50 | V |
| V _{CEO} | Collector-Emitter Voltage | 50 | V |
| V _{EBO} | Emitter-Base Voltage | 10 | V |
| I _C | Collector Current | 100 | mA |
| P _C | Collector Power Dissipation | 300 | mW |
| T _J | Junction Temperature | 150 | °C |
| T _{STG} | Storage Temperature | -55 ~ 150 | °C |



$\textbf{Electrical Characteristics} \ \, \textbf{T}_{a} \!\!=\!\! 25^{\circ} \textbf{C} \ \, \text{unless otherwise noted}$

| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units |
|-----------------------------------|--------------------------------------|---|------|------|------|-------|
| BV _{CBO} | Collector-Base Breakdown Voltage | $I_{C}=10\mu A, I_{E}=0$ | 50 | | | V |
| BV _{CEO} | Collector-Emitter Breakdown Voltage | I _C =100μA, I _B =0 | 50 | | | V |
| I _{CBO} | Collector Cut-off Current | V_{CB} =40V, I_{E} =0 | | | 0.1 | μΑ |
| h _{FE} | DC Current Gain | V _{CE} =5V, I _C =10mA | 20 | | | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I _C =10mA, I _B =0.5mA | | | 0.3 | V |
| f _T | Current Gain Bandwidth Product | V _{CE} =10V, I _C =5mA | | 250 | | MHz |
| f _T C _{ob} | Output Capacitance | V _{CB} =10V, I _E =0 f=1.0MHz | | 3.7 | | pF |
| V _I (off) | Input Off Voltage | $V_{CE}=5V, I_{C}=100\mu A$ | 0.5 | | | V |
| V _I (on) | Input On Voltage | V _{CE} =0.3V, I _C =20mA | | | 3 | V |
| R ₁ | Input Resistor | | 3.2 | 4.7 | 6.2 | ΚΩ |
| R ₁ /R ₂ | Resistor Ratio | | 0.9 | 1 | 1.1 | |

Typical Characteristics

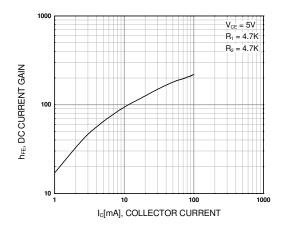


Figure 1. DC current Gain

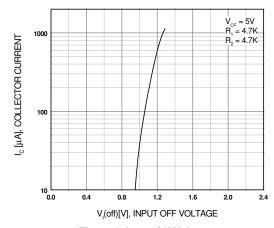


Figure 3. Input Off Voltage

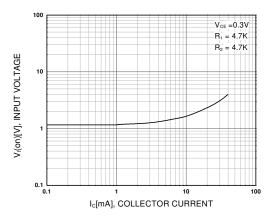


Figure 2. Input On Voltage

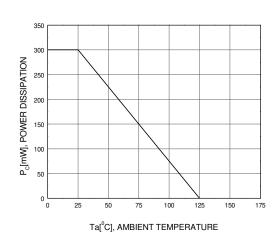
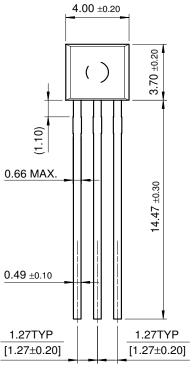
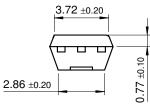
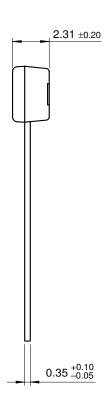


Figure 4. Power Derating

TO-92S







Dimensions in Millimeters

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| EnSigna™ | I ² C TM | OCX™ | RapidConfigure™ | UHC™ |
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